

## MM54HC195/MM74HC195 4-Bit Parallel Shift Register

#### **General Description**

The MM54HC195/MM74HC195 is a high speed 4-bit SHIFT REGISTER utilizes advanced silicon-gate CMOS technology to achieve the low power consumption and high noise immunity of standard CMOS integrated circuits, along with the ability to drive 10 LS-TTL loads at LS type speeds.

This shift register features parallel inputs, parallel outputs, J- $\overline{K}$  serial inputs, SHIFT/LOAD control input, and a direct overriding CLEAR. This shift register can operate in two modes: PARALLEL LOAD; SHIFT from Q<sub>A</sub> towards Q<sub>D</sub>.

Parallel loading is accomplished by applying the four bits of data, and taking the SHIFT/LOAD control input low. The data is loaded into the associated flip flops and appears at the outputs after the positive transition of the clock input. During parallel loading, serial data flow is inhibited. Serial shifting occurs synchronously when the SHIFT/LOAD con-

trol input is high. Serial data for this mode is entered at the J- $\overline{K}$  inputs. These inputs allow the first stage to perform as a J- $\overline{K}$  or TOGGLE flip flop as shown in the truth table.

The 54HC/74HC logic family is functionally as well as pinout compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to  $V_{CC}$  and ground.

#### **Features**

- Typical operating frequency: 45 MHz
- Typical propagation delay: 16 ns (clock to Q)
- Wide operating supply voltage range: 2–6V
- Low input current: 1 μA maximum
- Low quiescent current: 80 µA maximum (74HC Series)
- Fanout of 10 LS-TTL loads

#### **Connection Diagram**

**Dual-In-Line Package** OUTPUTS SHIFT/ QD CLOCK LOAD QA QC QD ۷сс QB 12 10 16 15 13 111 0 QA QB QC QD α<sub>D</sub> ск SHIFT CLEAR LOAD Δ в С D 3 6 8 CLEAR ĸ в С Ð GND J PARALLEL INPUTS SERIAL INPUTS TL/F/5324-1



#### Order Number MM54HC195 or MM74HC195

## **Function Table**

Inputs							Outputs						
Clear	Shift/	Clock	Se	rial	F	Par	alle	el	QA	QB	QC	QD	$\overline{Q}_{D}$
oicai	Load	Olock	J	ĸ	A	в	С	D		αB	чc	αD	αD
L	Х	Х	Х	Х	X	Х	Х	Х	L	L	L	L	Н
н	L	1	Х	Х	a	b	с	d	a	b	с	d	d
н	н	Ĺ	Х	Х	X	Х	Х	Х	Q <sub>A0</sub>	Q <sub>B0</sub>	Q <sub>C0</sub>	$Q_{D0}$	$\overline{Q}_{D0}$
н	Н	1	L	н	X	Х	Х		Q <sub>A0</sub>				Q <sub>Cn</sub>
н	Н	1	L	L	X	Х	Х	Х	Ĺ	Q <sub>An</sub>	Q <sub>Bn</sub>		
н	н	1	Н	н	X	Х	Х	Х	Н	Q <sub>An</sub>	Q <sub>Bn</sub>		
н	н	1	Н	L	X	Х	Х	Х	$\overline{Q}_{An}$	Q <sub>An</sub>	Q <sub>Bn</sub>		$\overline{Q}_{Cn}$

H = high level (steady state)

L = low level (steady state) X = irrelevant (any input, including transitions)

 $\uparrow$  = transition from low to high level

a, b, c, d = the level of steady-state input at inputs A, B, C, or D, respectively.

 $Q_{A0}$ ,  $Q_{B0}$ ,  $Q_{C0}$ ,  $Q_{D0}$  = the level of  $Q_A$ ,  $Q_B$ ,  $Q_C$ , or  $Q_D$ , respectively, before the indicated steady-state input conditions were established.

 $Q_{An}$ ,  $Q_{Bn}$ ,  $Q_{Cn}$  = the level of  $Q_A$ ,  $Q_B$ ,  $Q_C$ , respectively, before the most-recent transition of the clock.

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#### Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

-0.5 to +7.0V

 $\pm$  20 mA

 $\pm 25 \text{ mA}$ 

 $\pm$  50 mA

600 mW

500 mW

260°C

 $-\,1.5$  to  $V_{CC}\,{+}\,1.5V$ 

-0.5 to  $V_{CC}\!+\!0.5V$ 

-65°C to +150°C

Supply Voltage (V<sub>CC</sub>)

DC Input Voltage (VIN)

Power Dissipation (P<sub>D</sub>)

S.O. Package only

(Note 3)

DC Output Voltage (V<sub>OUT</sub>)

Clamp Diode Current (I<sub>IK</sub>, I<sub>OK</sub>)

DC Output Current, per pin (I<sub>OUT</sub>)

DC V<sub>CC</sub> or GND Current, per pin (I<sub>CC</sub>)

Storage Temperature Range (T<sub>STG</sub>)

Lead Temp. (T<sub>L</sub>) (Soldering 10 seconds)

## **Operating Conditions**

Supply Voltage (V <sub>CC</sub> )	Min 2	<b>Max</b> 6	Units V
DC Input or Output Voltage (V <sub>IN</sub> , V <sub>OUT</sub> )	0	$V_{CC}$	V
Operating Temp. Range (T <sub>A</sub> )			
MM74HC	-40	+85	°C
MM54HC	-55	+125	°C
Input Rise or Fall Times			
$(t_r, t_f) V_{CC} = 2.0V$		1000	ns
V <sub>CC</sub> =4.5V		500	ns
V <sub>CC</sub> =6.0V		400	ns

#### DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> =25°C		74HC T <sub>A</sub> = - 40 to 85°C	54HC T <sub>A</sub> = – 55 to 125°C	Units
				Тур		Guaranteed	1	
V <sub>IH</sub>	Minimum High Level Input Voltage		2.0V 4.5V 6.0V		1.5 3.15 4.2	1.5 3.15 4.2	1.5 3.15 4.2	V V V
V <sub>IL</sub>	Maximum Low Level Input Voltage**		2.0V 4.5V 6.0V		0.5 1.35 1.8	0.5 1.35 1.8	0.5 1.35 1.8	V V V
	Minimum High Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_{OUT}  \le 20 \ \mu A$	2.0V 4.5V 6.0V	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V V V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_{OUT}  \le 4.0 \text{ mA}$ $ I_{OUT}  \le 5.2 \text{ mA}$	4.5V 6.0V	4.2 5.7	3.98 5.48	3.84 5.34	3.7 5.2	V V
01	Maximum Low Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_{OUT}  \le 20 \ \mu A$	2.0V 4.5V 6.0V	0 0 0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V V V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_{OUT}  \le 4.0 \text{ mA}$ $ I_{OUT}  \le 5.2 \text{ mA}$	4.5V 6.0V	0.2 0.2	0.26 0.26	0.33 0.33	0.4 0.4	v v
I <sub>IN</sub>	Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0	μΑ
Icc	Maximum Quiescent Supply Current	$V_{IN} = V_{CC} \text{ or } GND$ $I_{OUT} = 0 \ \mu A$	6.0V		8.0	80	160	μΑ

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

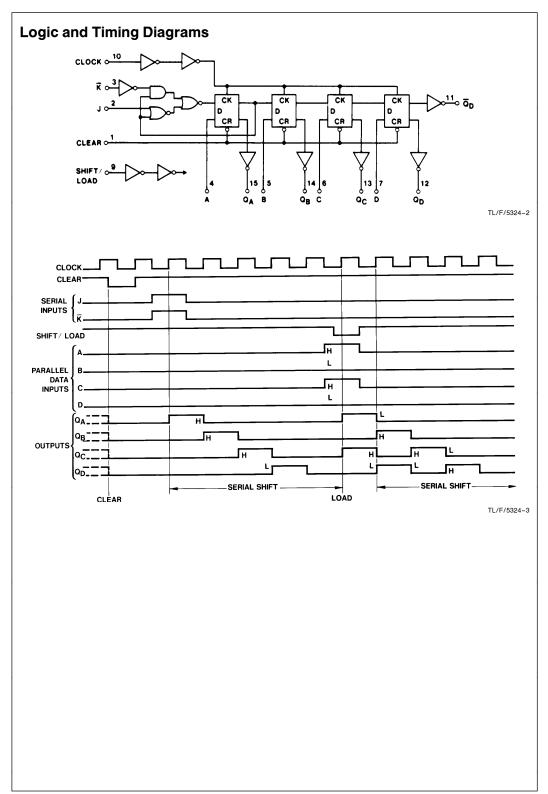
Note 3: Power Dissipation temperature derating — plastic "N" package:  $-12 \text{ mW/s}^{\circ}\text{C}$  from 65°C to 85°C; ceramic "J" package:  $-12 \text{ mW/s}^{\circ}\text{C}$  from 100°C to 125°C. Note 4: For a power supply of 5V  $\pm$ 10% the worst case output voltages (V<sub>OH</sub>, and V<sub>OL</sub>) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V<sub>IH</sub> and V<sub>IL</sub> occur at V<sub>CC</sub> = 5.5V and 4.5V respectively. (The V<sub>IH</sub> value at 5.5V is 3.85V.) The worst case leakage current (I<sub>IN</sub>, I<sub>CC</sub>, and I<sub>OZ</sub>) occur for CMOS at the higher voltage and so the 6.0V values should be used.

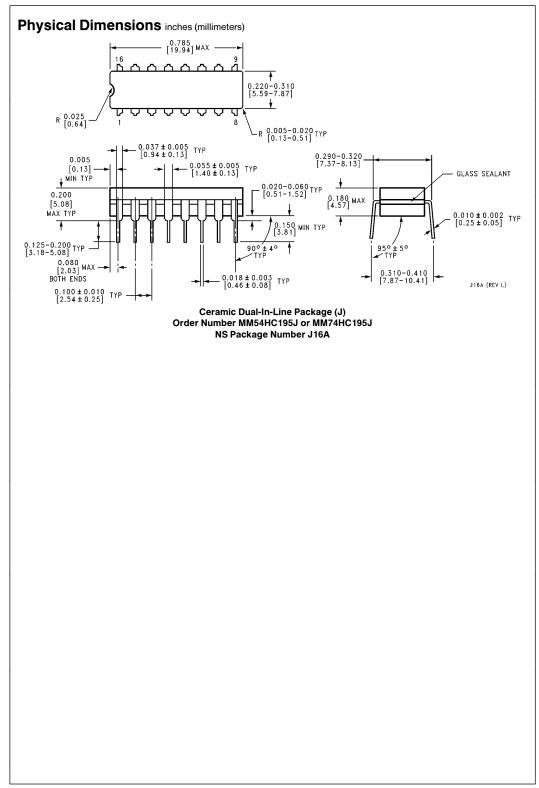
\*\*V<sub>IL</sub> limits are currently tested at 20% of V<sub>CC</sub>. The above V<sub>IL</sub> specification (30% of V<sub>CC</sub>) will be implemented no later than Q1, CY'89.

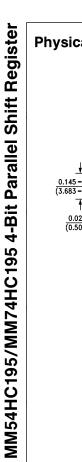
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
f <sub>MAX</sub>	Maximum Operating Frequency		45	30	MHz
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation Delay, Clock to Q		14	24	ns
t <sub>PHL</sub>	Maximum Propagation Delay, Reset to Q		16	25	ns
t <sub>REM</sub>	Minimum Removal Time, Shift/Load to Clock			0	ns
t <sub>REM</sub>	Minimum Removal Time, Reset Inactive to Clock			5	ns
ts	Minimum Setup Time, (A, B, C, D, J, K to Clock)			20	ns
ts	Minimum Setup Time, Shift/Load to Clock			20	ns
t <sub>W</sub>	Minimum Pulse Width Clock or Reset			16	ns
t <sub>H</sub>	Minimum Hold Time, any Input except Shift/Load			0	ns

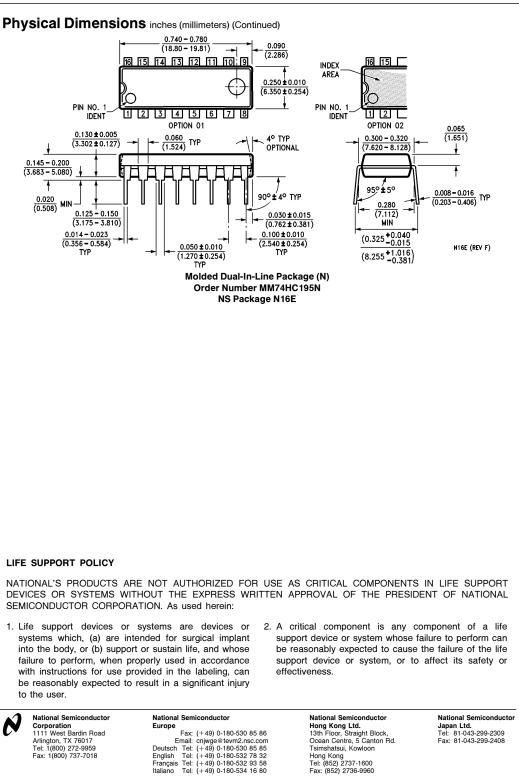
# AC Electrical Characteristics $C_L\!=\!50$ pF, $t_r\!=\!t_f\!=\!6$ ns (unless otherwise specified)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> =25°C		74HC T <sub>A</sub> = -40 to 85°C	54HC T <sub>A</sub> =-55 to 125°C	Units
				Тур		Guaranteed Limits		1
f <sub>MAX</sub>	Maximum Operating Frequency		2.0V 4.5V 6.0V	10 45 50	6 30 35	5 24 28	4 20 24	MHz MHz MHz
t <sub>PHL</sub>	Maximum Propagation Delay, Reset to Q or $\overline{Q}$		2.0V 4.5V 6.0V	70 15 12	150 30 26	189 38 32	224 45 38	ns ns ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation Delay, Clock to Q or $\overline{Q}$		2.0V 4.5V 6.0V	70 15 12	145 29 25	183 37 31	216 43 37	ns ns ns
t <sub>THL</sub> , t <sub>TLH</sub>	Maximum Output Rise and Fall Time		2.0V 4.5V 6.0V	30 8 7	75 15 13	95 19 16	110 22 19	ns ns ns
t <sub>REM</sub>	Minimum Removal Time, Shift Load to Clock		2.0V 4.5V 6.0V	-2 -2 -2	0 0 0	0 0 0	0 0 0	ns ns ns
t <sub>REM</sub>	Minimum Removal Time, Reset Inactive to Clock		2.0V 4.5V 6.0V		5 5 5	5 5 5	5 5 5	ns ns ns
ts	Minimum Setup Time, (A, B, C, D, J, K to Clock)		2.0V 4.5V 6.0V		100 20 17	125 25 21	150 30 25	ns ns ns
t <sub>S</sub>	Minimum Setup Time, Shift/Load to Clock		2.0V 4.5V 6.0V		100 20 17	125 25 21	150 30 25	ns ns ns
t <sub>H</sub>	Minimum Hold Time any Input except Shift/Load		2.0V 4.5V 6.0V	-10 -2 -2	0 0 0	0 0 0	0 0 0	ns ns ns
tw	Minimum Pulse Width, Clock or Reset		2.0V 4.5V 6.0V	30 10 9	80 16 14	100 20 18	120 24 20	ns ns ns
t <sub>r</sub> , t <sub>f</sub>	Maximum Input Rise and Fall Time		2.0V 4.5V 6.0V		1000 500 400	1000 500 400	1000 500 400	ns ns ns
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)			100				pF
C <sub>IN</sub>	Maximum Input Capacitance			5	10	10	10	pF









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